

Product Specification

PE4305

50 Ω RF Digital Attenuator 5-bit, 15.5 dB, DC - 4.0 GHz

Features

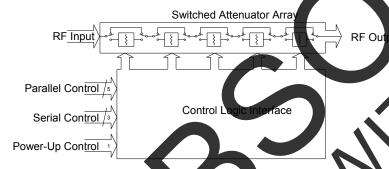
- Attenuation: 0.5 dB steps to 15.5 dB
- Flexible parallel and serial programming interfaces
- Latched or direct mode
- Unique power-up state selection
- Positive CMOS control lo
- High attenuation accuracy and linearity wer temperature and frequency
- Very low power consumption
- Single-supply operation
- Ω impedance
- Pin compatible with PE430x series Packaged in a 20 Lead 4x4 mm QFN

Product Description

The PE4305 is a high linearity, 5-bit RF Digital Step Attenuator (DSA) covering a 15.5 dB attenuation range in 0.5 dB steps. and is pin compatible with the PE430x series. This 50-ohm RF DSA provides both parallel (latched or direct mode) and serial CMOS control interface, operates on a single 3-volt supply and maintains high attenuation accuracy over frequency and temperature. It also has a unique control interface that allows the user to select an initial attenuation state at power-up. The PE4305 exhibits very low insertion loss and low power consumption. This functionality is delivered in a 4x4 mm QFN footprint.

The PE4305 is manufactured on Peregrine's UltraCMOS™ process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate, offering the performance of GaAs with the economy and integration of conventional CMOS.

Figure 1. Functional Schematic Diagram



ackage Type



Table 1. Electrical Specifications

Parameter	Test Conditions	Frequency	Minimum	Typical	Maximum	Units
Operation Frequency			DC		4000	MHz
Insertion Loss ²		DC - 2.2 GHz	-	1.5	2.25	dB
Attenuation Accuracy	Any Bit or Bit Combination	DC - 2.2 GHz	-	-	±(0.25 + 3% of atten setting) not to exceed ± 0.4 dB	dB
1 dB Compression ³		1 MHz - 2.2 GHz	30	34	-	dBm
Input IP3 ^{1, 2}	Two-tone inputs +18 dBm	1 MHz - 2.2 GHz	-	52	-	dBm
Return Loss		DC - 2.2 GHz	15	20	-	dB
Switching Speed	50% control to 0.5 dB of final value		-	-	1	μS

Notes: 1. will begin to degrade below 1Mhz

- but rating in Table 3 & Figures on Pages 2 to 4 for data across frequency.
- Absolute Maximum in Table 3.

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Typical Performance Data @ 25°C, V_{DD} = 3.0 V

Figure 3. Insertion Loss

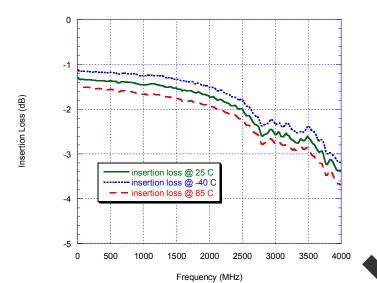


Figure 4. Attenuation at Major steps

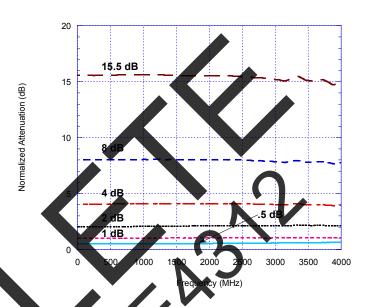


Figure 5. Input Return Loss at Major **Attenuation Steps**

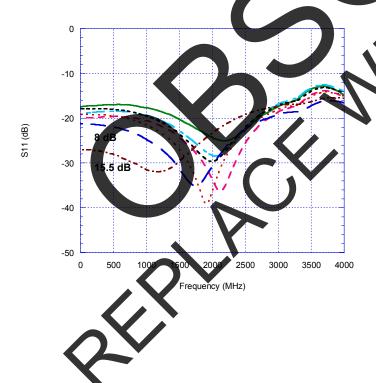
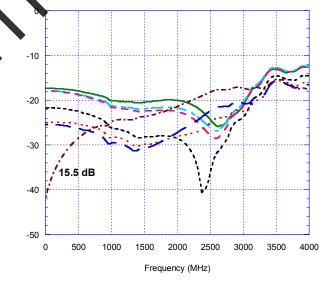


Figure 6. Output Return Loss at Major Attenuation Steps



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Typical Performance Data @ 25°C, V_{DD} = 3.0 V

Figure 7. Attenuation Error Vs. Frequency

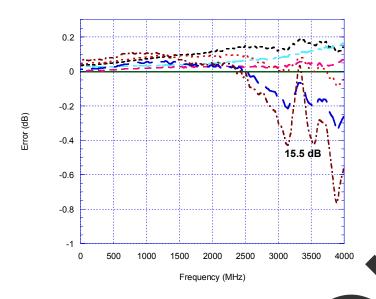


Figure 8. Attenuation Error Vs. Attenuation Setting at 10 MHz and 510 MHz

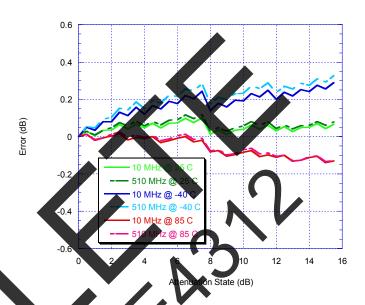
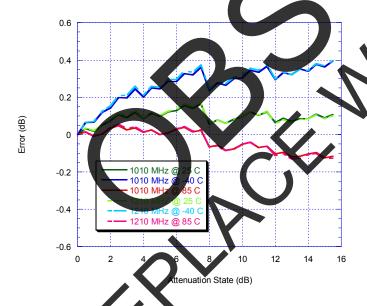
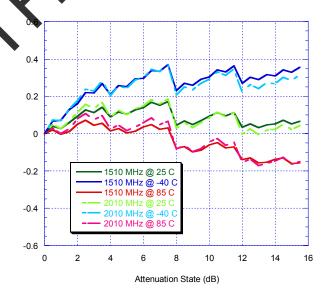


Figure 9. Attenuation Error Vs. Attenuation Setting 1010 MHz and 14



gure 10. Attenuation Error Vs. Attenuation Setting at 1510 MHz and 2010 MHz



Note: Posit Perror indicates higher attenuation than target value



Typical Performance Data @ 25°C, V_{DD} = 3.0 V

Figure 11. Attenuation Error vs. Attenuation

Setting at 2010 MHz and 2510 MHz

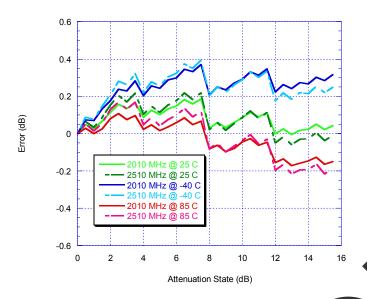


Figure 12. 1 dB Compression vs. Frequency

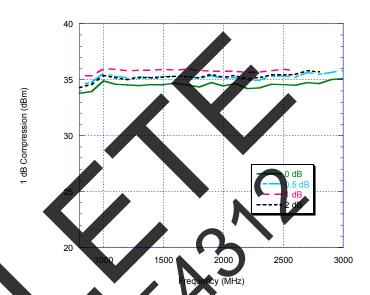
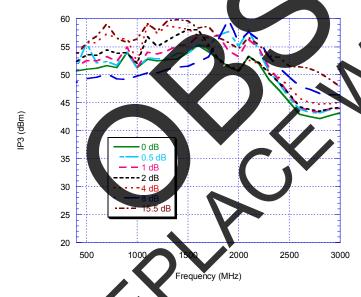


Figure 13. Input IP3 vs. Frequency



Note: Posi error indicates higher attenuation than target value



Figure 14. Pin Configuration (Top View)

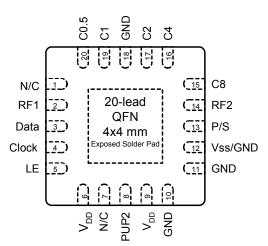


Table 2. Pin Descriptions

<u> </u>				
Pin No.	Pin Name	Description		
1	N/C	No connect. Can be connected to any bias.		
2	RF1	RF port (Note 1).		
3	Data	Serial interface data input (Note 4).		
4	Clock	Serial interface clock input.		
5	LE	Latch Enable input (Note 2).		
6	V_{DD}	Power supply pin.		
7	N/C	No connect. Can be connected to any bias.		
8	PUP2	Power-up selection bit.		
9	V_{DD}	Power supply pin.		
10	GND	Ground connection.		
11	GND	Ground connection.		
12	V _{ss} /GND	Negative supply voltage or GND connection(Note 3)		
13	P/S	Parallel/Serial mode select.		
14	RF2	RF port (Note 1).		
15	C 8	Attenuation control bit, 8 dB.		
16	C4	Attenuation control bit, 4 dB		
17	C2	Attenuation control bit, 2 dB.		
18	GND	Ground connection.		
19	C1	Attenuation control bit, 1 dB.		
20	C0.5	Attenuation control bit, 0.5 dB.		
Paddle	GND	Ground for proper operation		

Note 1: Both RF ports must be held at 0 VDC or DC blocked with an external series capacitor.

- 2: Latch Enable (LE) has an internal 100 kΩ resistor to VDD.
- 3: Connect pin 12 to GND to enable internal negative voltage generator. Connect pin 12 to VSS (-VDD) to bypass and disable internal negative voltage generator.
- 4. Place 10 kg resistor in series, as close to pin as possible to avoid frequency resonance. See "Resistor on Pin 3" paragraph.

Table 3. Absolute Maximum Ratings

Symbol	Parameter/Conditions	Min	Max	Units
V_{DD}	Power supply voltage	-0.3	4.0	V
Vı	Voltage on any DC input	-0.3	V _{DD} + 0.3	٧
T _{ST}	Storage temperature range	-65	150	°C
P _{IN}	Input power (50Ω)		+30	dBm
V _{ESD}	ESD voltage (Human Body Model)		500	V

Exceeding absolute maximum ratings may cause permanent damage. Operation should be restricted to the limits in the Operating Ranges table. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

Table 4. Operating Ranges

Parameter	Min	Тур	Max	Units
V _{DD} Power Supply Voltage	2.7	3.0	3.3	V
I _{DD} Power Supply Current)	100	μΑ
Digital Input High	0.7xV _{DD}			V
Digital Input Low			$0.3xV_{DD}$	V
Digital Input Leakage			1	μΑ
Input Patver			+24	dBm
Temperature range	-40		85	°C

Exposed Solder Pad Connection

The exposed solder pad on the bottom of the package must be grounded for proper device operation.

Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS[™] device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the rate specified in Table 3.

Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS™ devices are immune to latch-up.

Switching Frequency

The PE4305 has a maximum 25 kHz switching rate.

Resistor on Pin 3

A 10 $k\Omega$ resistor on the input to Pin 3 (see Figure 16) will eliminate package resonance between the RF input pin and the digital input. Specified attenuation error versus frequency performance is dependent upon this condition.



Programming Options

Parallel/Serial Selection

Either a parallel or serial interface can be used to control the PE4305. The P/S bit provides this selection, with P/S=LOW selecting the parallel interface and P/S=HIGH selecting the serial interface.

Parallel / Direct Mode Interface

The parallel interface consists of five CMOScompatible control lines that select the desired attenuation state, as shown in Table 5.

The parallel interface timing requirements are defined by Figure 18 (Parallel Interface Timing Diagram), Table 9 (Parallel Interface AC Characteristics), and switching speed (Table 1).

For parallel programming the Latch Enable (LE) should be held LOW while changing attenuation state control values, then pulse LE HIGH to LOW (per Figure 18) to latch new attenuation state into device.

For direct programming, the Latch Enable (LE) Ine should be pulled HIGH. Changing attenuation state control values will change device state to new attenuation. Direct Mode is ideal for manual conof the device (using hardwire, switches, or jumpers).

Table 5. Truth Table

P/S	C8	C4	C2	C1	CO.5	Attenuation State
0	0	0	0	0	0	Reference Loss
0	0	0		0	1	Ø 5 dB
0	0	0	0	1	0	1 dB
0	0	0	1	Q	0	2 dB
0	0	1	0	Ø	0	4 dB
0	1	0	0	0	0	8 dB
0	1	1	7	1	1	15.5 dB

Note: Not all 32 possible combinations of C 5-C8 are shown in table

Serial Interface

The PE4305's serial merface is a 6-bit serial-in. parallel-out shift register buffered by a transparent latch. The latch is controlled by three CMOScompatible signals: Data, Clock, and Latch Enable ata and Clock inputs allow data to be (LE). T

serially entered into the shift register, a process that is independent of the state of the LE input.

The LE input controls the latch. When LE is HIGH, the latch is transparent and the contents of the serial shift register control the attenuator. When LE is brought LOW, data in the shift register is latched.

The shift register should be loaded while LE is held LOW to prevent the attenuator value from changing as data is entered. The LE input should then be toggled HIGH and brought LQW again, fatching the new data. The stan bit (B5) of the data should always be low to prevent an unknown state in the device. The timing for this operation is defined by Figure 17 (Serial Interface Timing Diagram) and Table 8 (Serial Interface AC Characteristics)

Power-up Control Settings

The PE4305 always assumes a specifiable attenuation setting on power-up. This feature exists for both the Serial and Parallel modes of operation, and allows a known attenuation state to be ablished before an initial serial or parallel control word is provided.

When the attenuator powers up in Serial mode (P/ S=1), the five control bits are set to whatever data is present on the five parallel data inputs (C0.5 to C8). This allows any one of the 32 attenuation settings to e specified as the power-up state.

When the attenuator powers up in Parallel mode (P/ ►0) with LE=0, the control bits are automatically set to one of two possible values. These two values are selected by the power-up control bit, PUP2, as shown in Table 6 (Power-Up Truth Table, Parallel Mode).

Table 6. Power-Up Truth Table, Parallel Interface Mode

P/S	LE	PUP2	Attenuation State
0	0	0	Reference Loss
0	0	1	8 dB
0	1	Х	Defined by C0.5-C8

Note: Power up with LE=1 provides normal parallel operation with C0.5-C8, and PUP2 is not active



Evaluation Kit

The Digital Attenuator Evaluation Kit board was designed to ease customer evaluation of the PE4305 DSA.

J9 is used in conjunction with the supplied DC cable to supply VDD, GND, and -VDD. If use of the internal negative voltage generator is desired, then connect -VDD (black banana plug) to ground. If an external -VDD is desired, then apply -3V.

J1 should be connected to the LPT1 port of a PC with the supplied control cable. The evaluation software is written to operate the DSA in serial mode, so switch 7 (P/S) on the DIP switch SW1 should be ON with all other switches off. Using the software, enable or disable each attenuation setting to the desired combined attenuation. The software automatically programs the DSA each time an attenuation state is enabled or disabled.

To evaluate the Power Up options, first disconnect the control cable from the evaluation board. The control cable must be removed to prevent the PC port from biasing the control pins.

During power up with P/S=1 high and LE=0 or P/S=0 low and LE=1, the default power-up signal attenuation is set to the value present on th control bits on the five parallel data inputs (C0.5 to C8). This allows any one of the 32 attenuation settings to be specified as the power-up state.

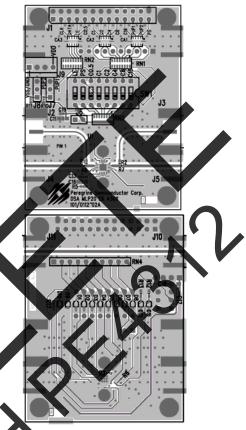
During power up with P/S=0 high and LE=0, the control bits are automatically set to possible values presented through the interface. These two values are selected by the power-up control bit, PUP2, shown in Table 6. Pins 1 and 7 are open and may be connected to any bias.

Resistor on Pin 3

A 10 k Ω resistor on the input to pin 3 (Figure 16) will eliminate package resonance between the RF input pin and the digital input. Specified attenuation error versus frequency performance is dependent upon this condition.

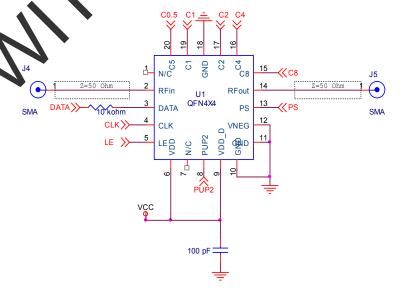
Figure 15. Evaluation Board Layout

Peregrine Specification 101/0112



16. Evaluation Board Schematic

regrine Specification 102/0144



Note: Resistor on pin 3 is required and should be placed as close to the part as possible to avoid package resonance and meet error specifications over frequency.

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Figure 17. Serial Interface Timing Diagram

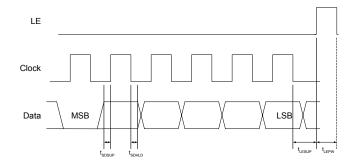


Figure 18. Parallel Interface Timing Diagram

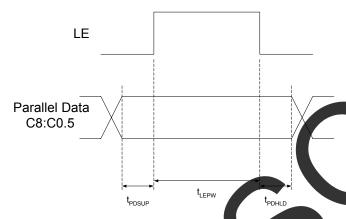


Table 8. Serial Interface AC Characteristics

 $V_{DD} = 3.0 \text{ V}, -40^{\circ} \text{ C} < T_A < 85$

Symbol	Parameter	Min	Max	Unit
f_{Clk}	Serial data clock frequency (Note 1)		10	MHz
t_{ClkH}	Serial clock HIGH time	30		ns
t_{ClkL}	Serial clock LOW time	30	1	ns
t _{LESUP}	LE set-up time after last clock falling edge	10		ns
t_{LEPW}	LE minimum pulse width	8) ,	ns
t _{SDSUP}	Serial data set-up time before clock rising edge	10		ns
t _{SDHLD}	Serial data held time after clock falling edge	10		ns

Note: f_{Clk} is verified during the functional pattern test. Serial e functional pattern are clocked at cification.

Table 7. 5-Bit Attenuator Serial Programming Register Map

	B5	B4	В3	B2	B1	В0
	0	C8	C4	C2	C1	C0.5
ı	↑ MSB (first	t in)			<u> </u>	↑ SB (last in

Note: The start bit (B5) m ne attenuator from entering an known state.

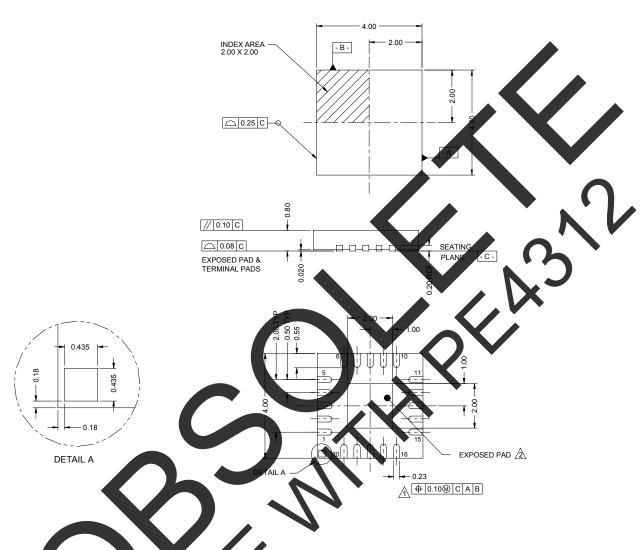


Symbol	Parameter	Min	Max	Unit
t _{LEPW}	LE minimum pulse width	10		ns
t _{PDSUP}	Data set-up time before rising edge of LE	10		ns
t _{PDHLD}	Data hold time after falling edge of LE	10		ns

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Figure 19. Package Drawing



to metallized terminal and is measured 30 from terminal tip. to the exposed heat sink slug as well as the imension

between 2. Copia anarity app termin

e in millimeters. Dim

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Figure 20. Marking Specifications

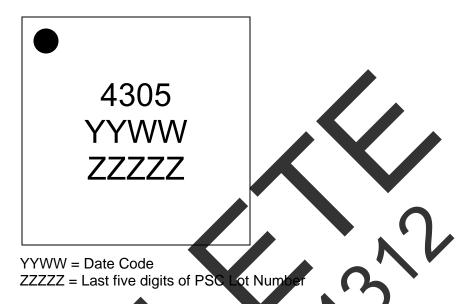


Figure 21. Tape and Reel Drawing

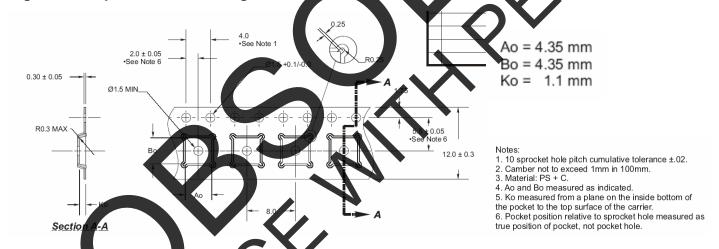


Table 10. Ordering Information

Order Code	Part Marking	Description	Package	Shipping Method
4305-00	PE4305-EK	PE4305-20MLP 4x4mm-EK	Evaluation Kit	1 / Box
4305-51	4305	PE4305G-20MLP 4x4mm-75A	Green 20-lead 4x4mm QFN	75 units / Tube
4305-52	4305	PE4305G-20MLP 4x4mm-3000C	Green 20-lead 4x4mm QFN	3000 units / T&R



Sales Offices

The Americas

Peregrine Semiconductor Corporation

9380 Carroll Park Drive San Diego, CA 92121 Tel: 858-731-9400 Fax: 858-731-9499

Europe

Peregrine Semiconductor Europe

Bâtiment Maine 13-15 rue des Quatre Vents F-92380 Garches, France Tel: +33-1-4741-9173

Fax: +33-1-4741-9173

Space and Defense Products

Americas:

Tel: 858-731-9453

Europe, Asia Pacific:
180 Rue Jean de Guiramand

13852 Aix-En-Provence Cedex 3, France

Tel: +33-4-4239-3361 Fax: +33-4-4239-7227

Peregrine Semiconductor, Asia Pacific (APAC)

Shanghai, 200040, P.R. China Tel: +86-21-5836-8276 Fax: +86-21-5836-7652

Peregrine Semiconductor, Korea

#B-2607, Kolon Tripolis, 210

Geumgok-dong, Bundang-gu, Seongnam-si

Gyeonggi-do, 463-943 South Kore

Tel: +82-31-728-3939 Fax: +82-31-728-3940

Peregrine Semiconductor K.K., Japan

Teikoku Hotel Tower 10B-6 1-1-1 Uchrsaiwai-cho, Chiyoda-ku Tokyo 100-0011 Japan

Tel: +81 3-3502-5211 Fax: +81-3-3502-5213

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Data Sheet Identification

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Product Specification

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